



UT100N04

Power MOSFET

100A, 40V N-CHANNEL POWER MOSFET

DESCRIPTION

The UTC **UT100N04** is an N-channel power MOSFET using UTC's advanced technology to provide customers with a minimum on-state resistance and superior switching performance.

The UTC **UT100N04** is generally applied in low power switching mode power appliances and electronic ballast.

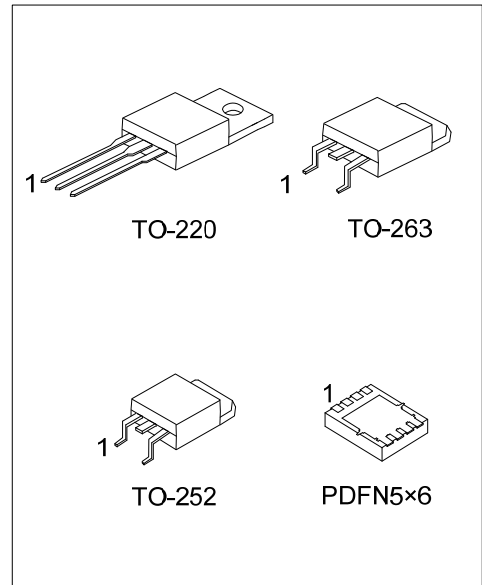
FEATURES

* $R_{DS(ON)} \leq 4.8 \text{ m}\Omega$ @ $V_{GS}=10\text{V}$, $I_D=50\text{A}$

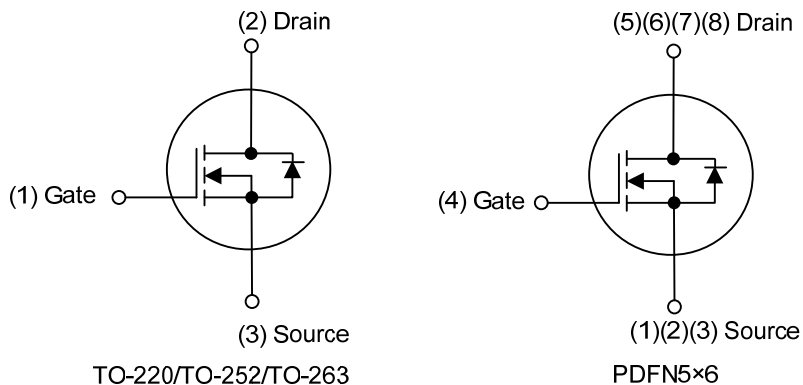
$R_{DS(ON)} \leq 6.5 \text{ m}\Omega$ @ $V_{GS}=4.5\text{V}$, $I_D=50\text{A}$

* High Switching Speed

* Improved dv/dt capability



SYMBOL



ORDERING INFORMATION

Ordering Number		Package	Pin Assignment								Packing
Lead Free	Halogen Free		1	2	3	4	5	6	7	8	
UT100N04L-TA3-T	UT100N04G-TA3-T	TO-220	G	D	S	-	-	-	-	-	Tube
UT100N04L-TN3-R	UT100N04G-TN3-R	TO-252	G	D	S	-	-	-	-	-	Tape Reel
UT100N04L-TQ2-T	UT100N04G-TQ2-T	TO-263	G	D	S	-	-	-	-	-	Tube
UT100N04L-TQ2-R	UT100N04G-TQ2-R	TO-263	G	D	S	-	-	-	-	-	Tape Reel
UT100N04L-P5060-R	UT100N04G-P5060-R	PDFN5x6	S	S	S	G	D	D	D	D	Tape Reel

Note: Pin Assignment: G: Gate D: Drain S: Source

UT100N04G-TA3-T		(1) T: Tube, R: Tape Reel (2) TA3: TO-220, TN3: TO-252, TQ2: TO-263 P5060: PDFN5x6 (3) G: Halogen Free and Lead Free, L: Lead Free
------------------------	--	--

■ MARKING

TO-220 / TO-252 / TO-263	PDFN5×6
UTC UT100N04 □ □ □ □ □ Lot Code ← → Date Code 1 L: Lead Free G: Halogen Free	UTC UT 100N04 • □□□□□ Lot Code ← → Date Code

■ **ABSOLUTE MAXIMUM RATINGS** (Unless otherwise specified)

PARAMETER		SYMBOL	RATINGS	UNIT
Drain-Source Voltage		V_{DSS}	40	V
Gate-Source Voltage		V_{GSS}	± 20	V
Continuous Drain Current		I_D	100	A
Pulsed Drain Current (Note 2)		I_{DM}	200	A
Avalanche Energy	Single Pulsed (Note 3)	E_{AS}	125	mJ
Peak Diode Recovery dv/dt		dv/dt	1.56	V/ns
Power Dissipation ($T_C=25^\circ\text{C}$)	TO-220/TO-263	P_D	73	W
	TO-252		60	W
	PDFN5×6		40	W
Junction Temperature		T_J	+150	$^\circ\text{C}$
Operation and Storage Temperature		T_{STG}	-55 ~ +150	$^\circ\text{C}$

Notes: 1. Absolute maximum ratings are those values beyond which the device could be permanently damaged.

Absolute maximum ratings are stress ratings only and functional device operation is not implied.

2. Repetitive Rating : Pulse width limited by maximum junction temperature.

3. $L=0.1\text{mH}$, $I_{AS}=50\text{A}$, $V_{DD}=25\text{V}$, $R_G=20\Omega$, Starting $T_J=25^\circ\text{C}$

4. $I_{SD} \leq 100\text{A}$, $V_{DS}=0\text{V}$, $di/dt \leq 200\text{A}/\mu\text{s}$, $V_{DD} \leq BV_{DSS}$, Starting $T_J = 25^\circ\text{C}$

■ **THERMAL DATA**

PARAMETER		SYMBOL	RATINGS	UNIT
Junction to Ambient	TO-220/TO-263	θ_{JA}	62.5	$^\circ\text{C}/\text{W}$
	TO-252		110	$^\circ\text{C}/\text{W}$
	PDFN5×6		40.3 (Note)	$^\circ\text{C}/\text{W}$
Junction to Case	TO-220/TO-263	θ_{JC}	1.7	$^\circ\text{C}/\text{W}$
	TO-252		2.08 (Note)	$^\circ\text{C}/\text{W}$
	PDFN5×6		3.12 (Note)	$^\circ\text{C}/\text{W}$

Note: Device mounted on FR-4 substrate P_C board, 2oz copper, with 1inch square copper plate.

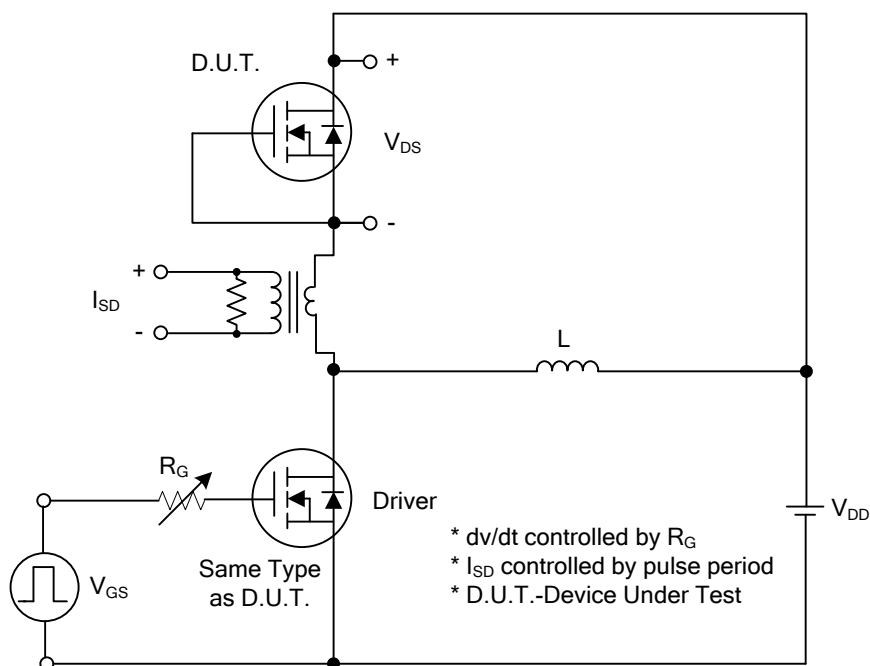
■ **ELECTRICAL CHARACTERISTICS** ($T_C = 25^\circ\text{C}$, unless otherwise specified)

PARAMETER		SYMBOL	TEST CONDITIONS	MIN	TYP	MAX	UNIT
OFF CHARACTERISTICS							
Drain-Source Breakdown Voltage		BV_{DSS}	$V_{GS}=0V, I_D=250\mu A$	40			V
Drain-Source Leakage Current		I_{DSS}	$V_{DS}=40V, V_{GS}=0V$			1	μA
Gate-Source Leakage Current	Forward	I_{GSS}	$V_{GS}=20V, V_{DS}=0V$			100	nA
	Reverse		$V_{GS}=-20V, V_{DS}=0V$			-100	nA
ON CHARACTERISTICS							
Gate Threshold Voltage		$V_{GS(TH)}$	$V_{DS}=V_{GS}, I_D=250\mu A$	1.0		3.0	V
Static Drain-Source On-State Resistance		$R_{DS(ON)}$	$V_{GS}=10V, I_D=50A$			4.8	m Ω
			$V_{GS}=4.5V, I_D=50A$			6.5	m Ω
DYNAMIC CHARACTERISTICS							
Input Capacitance		C_{ISS}	$V_{GS}=0V, V_{DS}=25V, f=1MHz$		3450		pF
Output Capacitance		C_{OSS}			640		pF
Reverse Transfer Capacitance		C_{RSS}			580		pF
SWITCHING CHARACTERISTICS							
Total Gate Charge		Q_G	$V_{DS}=20V, V_{GS}=10V, I_D=100A$ $I_G=1mA$ (Note1,2)		110		nC
Gate-Source Charge		Q_{GS}			12		nC
Gate-Drain Charge		Q_{GD}			25		nC
Turn-On Delay Time		$t_{D(ON)}$	$V_{DS}=20V, V_{GS}=10V, I_D=100A,$ $R_G=3\Omega$ (Note1,2)		12		ns
Turn-On Rise Time		t_R			19		ns
Turn-Off Delay Time		$t_{D(OFF)}$			79		ns
Turn-Off Fall Time		t_F			38		ns
DRAIN-SOURCE DIODE CHARACTERISTICS AND MAXIMUM RATINGS							
Maximum Continuous Drain-Source Diode Forward Current		I_S				100	A
Maximum Pulsed Drain-Source Diode Forward Current		I_{SM}				200	A
Drain-Source Diode Forward Voltage		V_{SD}	$I_S=100A, V_{GS}=0V$			1.4	V
Body Diode Reverse Recovery Time		t_{rr}	$I_S=50A, V_{GS}=0V,$		44.4		ns
Body Diode Reverse Recovery Charge		Q_{rr}	$dI_S/dt=100A/\mu s$		26		nC

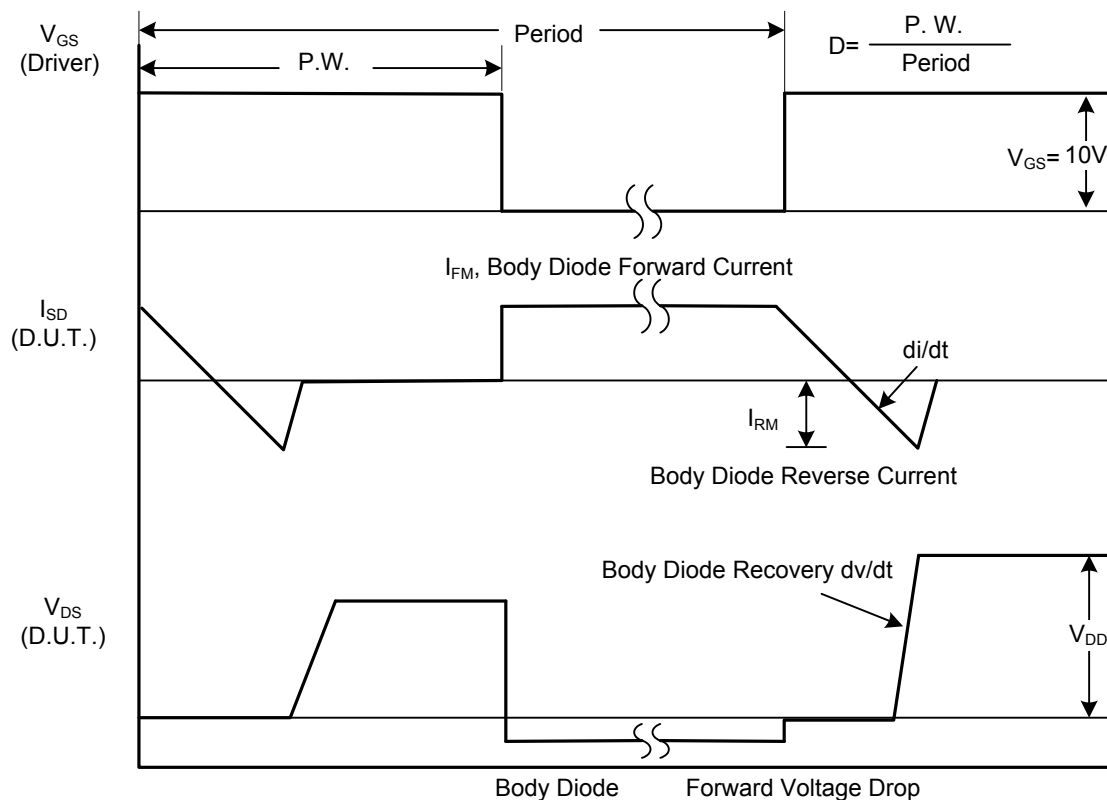
Notes: 1. Pulse Test: Pulse Width $\leq 300\mu s$, Duty Cycle $\leq 2\%$.

2. Essentially independent of operating temperature.

TEST CIRCUITS AND WAVEFORMS



Peak Diode Recovery dv/dt Test Circuit



Peak Diode Recovery dv/dt Waveforms

■ TEST CIRCUITS AND WAVEFORMS

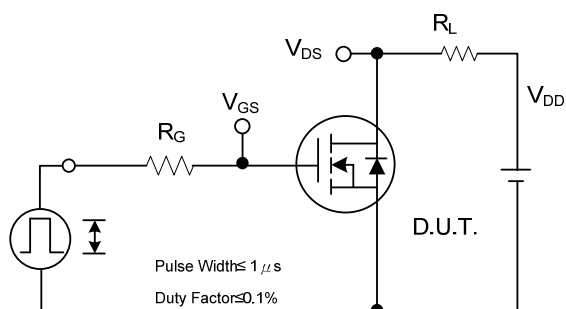


Fig. 2A Switching Test Circuit

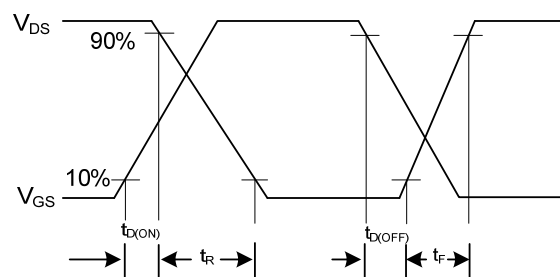


Fig. 2B Switching Waveforms

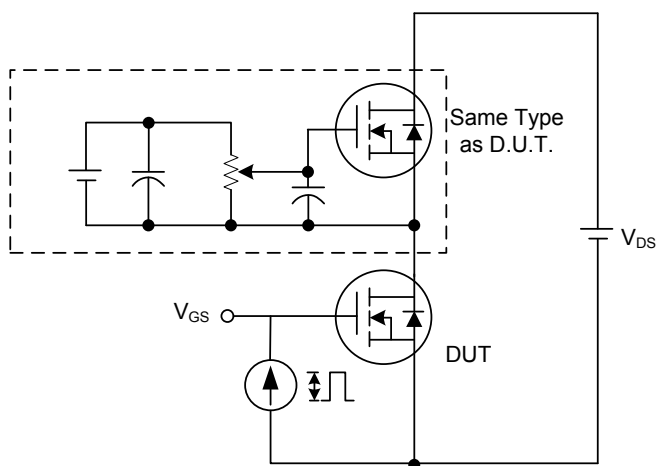


Fig. 3A Gate Charge Test Circuit

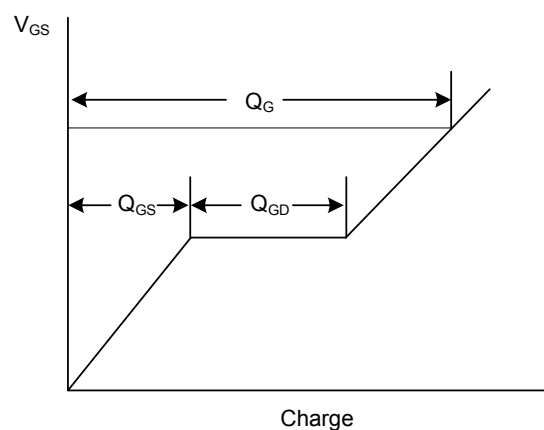


Fig. 3B Gate Charge Waveform

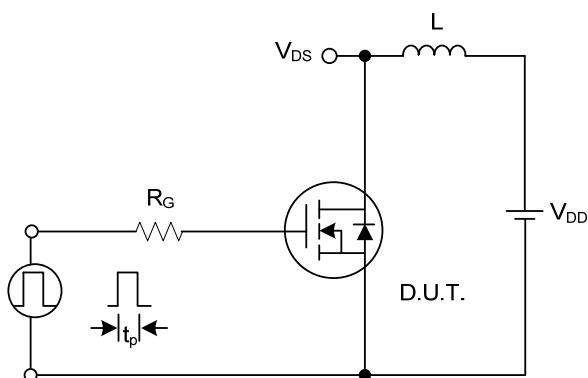


Fig. 4A Unclamped Inductive Switching Test Circuit

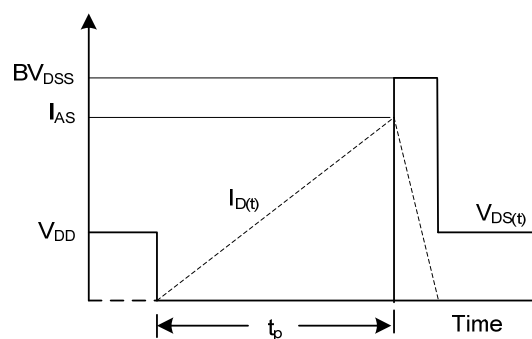
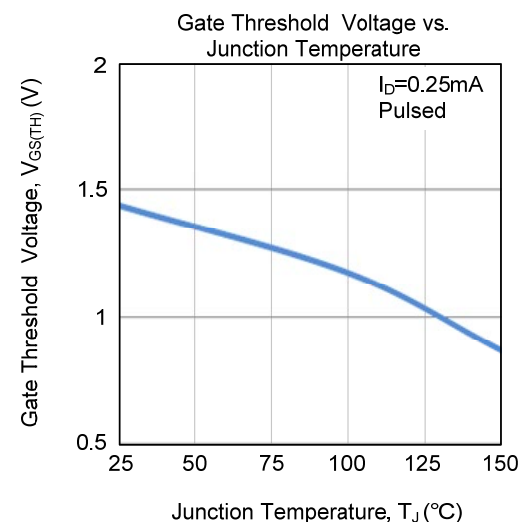
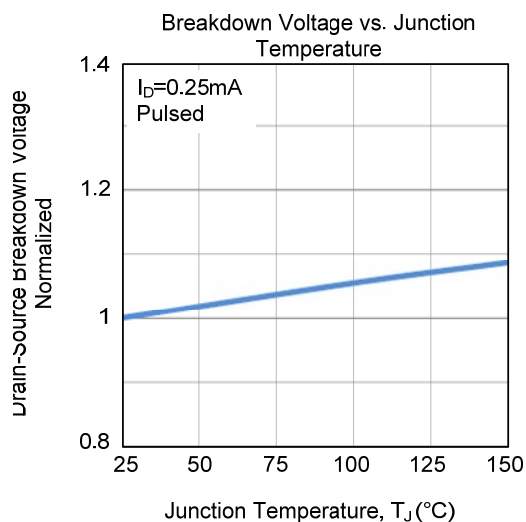
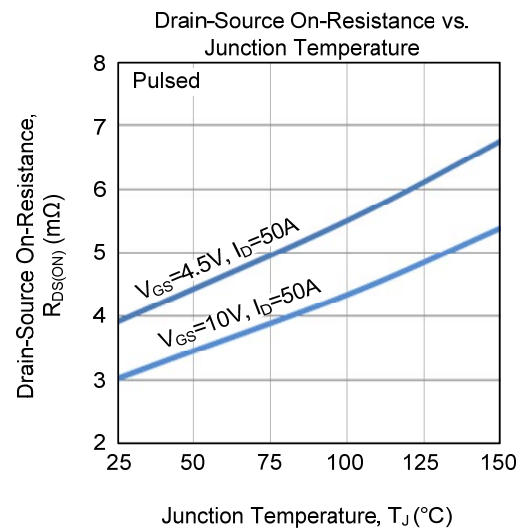
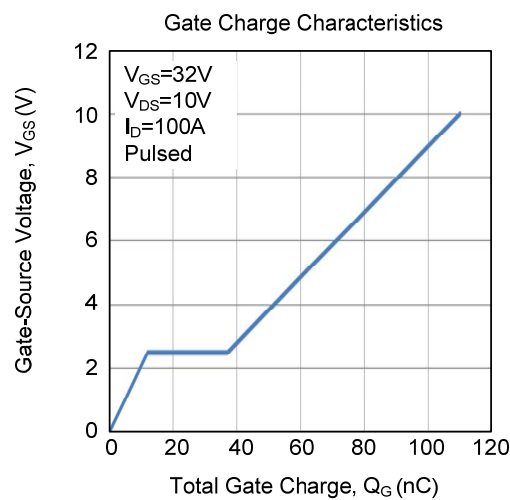
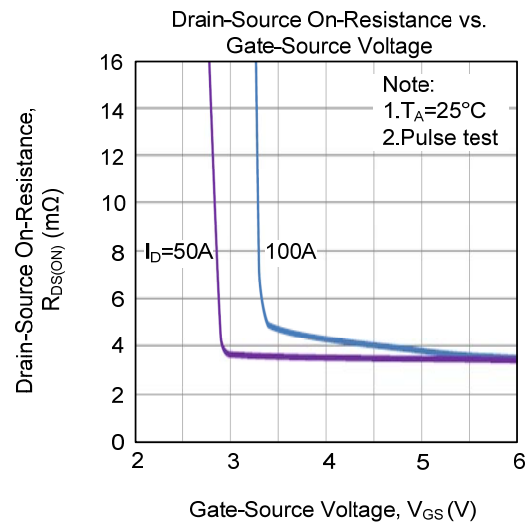
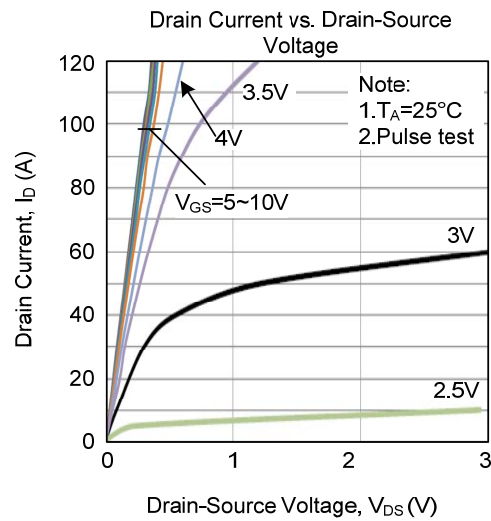
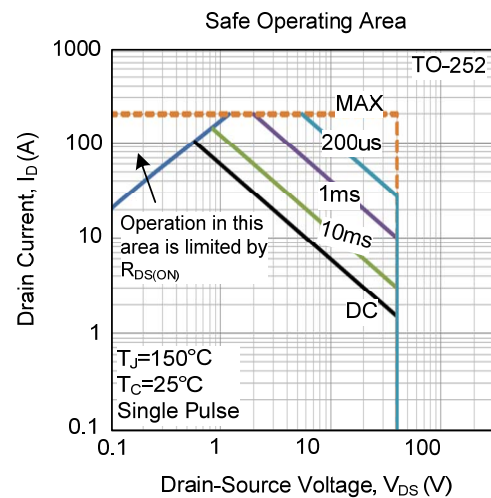
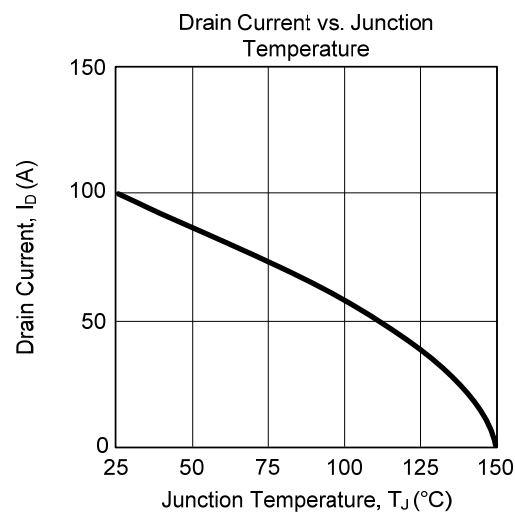
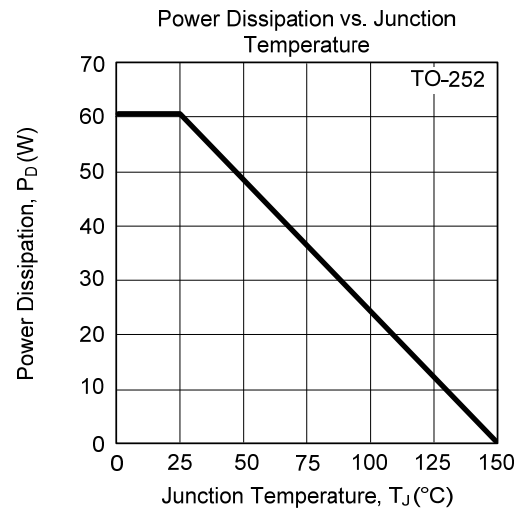
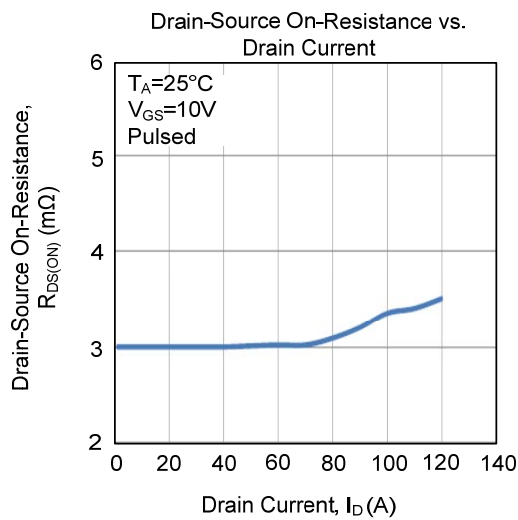
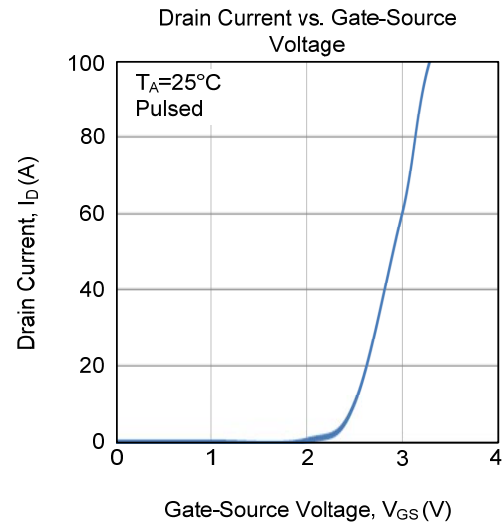
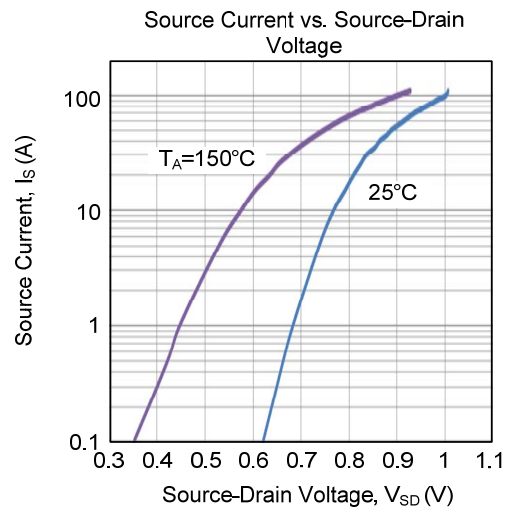


Fig. 4B Unclamped Inductive Switching Waveforms

TYPICAL CHARACTERISTICS



■ TYPICAL CHARACTERISTICS (Cont.)



UTC assumes no responsibility for equipment failures that result from using products at values that exceed, even momentarily, rated values (such as maximum ratings, operating condition ranges, or other parameters) listed in products specifications of any and all UTC products described or contained herein. UTC products are not designed for use in life support appliances, devices or systems where malfunction of these products can be reasonably expected to result in personal injury. Reproduction in whole or in part is prohibited without the prior written consent of the copyright owner. UTC reserves the right to make changes to information published in this document, including without limitation specifications and product descriptions, at any time and without notice. This document supersedes and replaces all information supplied prior to the publication hereof.